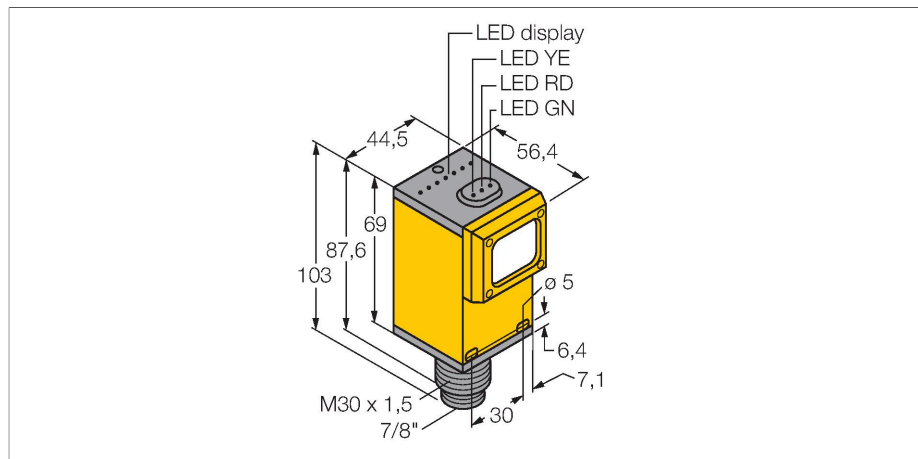


Q45BB6RQ

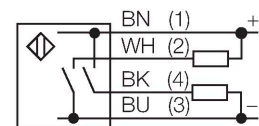
Photoelectric Sensor – Opposed Mode Sensor (Emitter/Receiver)



Features

- Male connector 7/8"
- Protection class IP67
- Sensitivity adjusted via potentiometer
- Operating voltage: 10...30 VDC
- Switching output, bipolar
- Light or dark operation, adjusted via switch

Wiring diagram



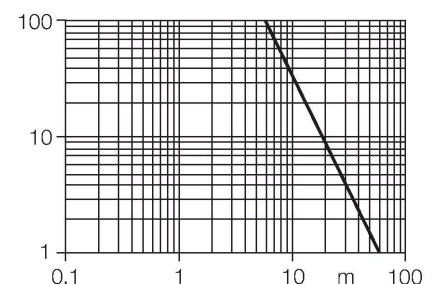
Technical data

Type	Q45BB6RQ
ID no.	3036731
Optical data	
Function	Opposed mode sensor
Operating mode	Receiver
Range	0...60000 mm
Electrical data	
Operating voltage	10...30 VDC
Residual ripple	< 10 % U _{ss}
No-load current	≤ 50 mA
Short-circuit protection	yes
Reverse polarity protection	yes
Output function	NO contact, PNP/NPN
Switching frequency	≤ 250 Hz
Readiness delay	≤ 100 ms
Response time typical	< 2 ms
Overcurrent release	> 220 mA
Setting option	Potentiometer
Mechanical data	
Design	Rectangular, Q45
Dimensions	Ø 30 x 56.4 x 44.5 x 101.6 mm
Housing material	Plastic, Thermoplastic material
Lens	plastic, Acrylic
Electrical connection	Connectors, 7/8", PVC
Number of cores	4
Ambient temperature	-40...+70 °C

Functional principle

Opposed mode sensors consist of an emitter and receiver. They are installed opposite each other so that the light from the emitter is aimed directly at the receiver. When an object interrupts or weakens the light beam, the sensor switches. Opposed mode sensors are the most reliable photoelectric sensors for detection of opaque targets. An excellent contrast between light and dark conditions and an extremely high excess gain are typical of this sensing mode, thus allowing operation over larger distances and under difficult conditions. Excess gain curve

Excess gain in relation to the distance



Technical data

Protection class	IP67
Special features	keep/defer
Power-on indication	LED, Green
Switching state	LED, Yellow
Error indication	LED, green, Flashing
Excess gain indication	LED, red
Tests/approvals	
MTTF	67 years acc. to SN 29500 (Ed. 99) 40 °C
Approvals	CE, cURus, CSA

Accessories

